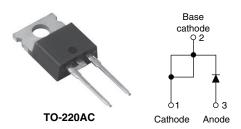


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HALOGEN

FREE

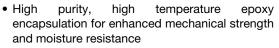
Schottky Rectifier, 19 A



PRODUCT SUMMARY					
Package	TO-220AC				
I _{F(AV)}	19 A				
V_{R}	15 V				
V _F at I _F	0.32 V				
I _{RM} max.	522 mA at 100 °C				
T _J max.	125 °C				
Diode variation	Single die				
E _{AS}	6.75 mJ				

FEATURES

- 125 °C T_J operation (V_R < 5 V)
- · Optimized for OR-ing applications
- Ultralow forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

The VS-19TQ015... Schottky rectifier has been optimized for ultralow forward voltage drop specifically for the OR-ing of parallel power supplies. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	19	A			
V _{RRM}		15	V			
I _{FSM}	t _p = 5 μs sine	700	Α			
V _F	19 A _{pk} , T _J = 75 °C	0.32	V			
TJ	Range	- 55 to 125	°C			

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-19TQ015PbF	VS-19TQ015-N3	UNITS
Maximum DC reverse voltage	V _R	15	15	V
Maximum working peak reverse voltage	V_{RWM}] 15	15	V

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS	
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 80 °C,	19			
Maximum peak one cycle non-repetitive surge current	1	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	700	Α	
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	330		
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1.50 A, L = 6 mH		6.75	mJ	
Repetitive avalanche current	I _{AR}	Current decaying linearly to zer Frequency limited by T _J maxim		1.50	Α	

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VS-19TQ015PbF, VS-19TQ015-N3

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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
		19 A	T 05.00	0.36	V	
Maximum forward voltage drop	V _{FM} ⁽¹⁾	38 A	T _J = 25 °C	0.46		
See fig. 1	VFM (')	19 A	T 75 °C	0.32		
		38 A	- T _J = 75 °C	0.43		
	I _{RM} ⁽¹⁾	T _J = 100 °C, V _R = 12 V		465	m A	
Maximum reverse leakage current		T _J = 100 °C, V _R = 5 V		285		
See fig. 2		T _J = 25 °C	V Datady	10.5	mA	
		T _J = 100 °C	V _R = Rated V _R	522		
Maximum junction capacitance	C _T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		2000	pF	
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		8.0	nH	
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs		

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction temperature range		TJ		- 55 to 125	°C	
Maximum storage tempo	erature range	T _{Stg}		- 55 to 150		
Maximum thermal resistance, junction to case		R _{thJC}	DC operation See fig. 4	1.50	°C/W	
Typical thermal resistan case to heatsink	ce,	R _{thCS}	Mounting surface, smooth and greased	0.50	C/VV	
Approximate weight				2	g	
Approximate weight				0.07	OZ.	
Mounting torque	minimum			6 (5)	kgf · cm	
	maximum			12 (10)	(lbf · in)	
Marking device			Case style TO-220AC	19TQ015		

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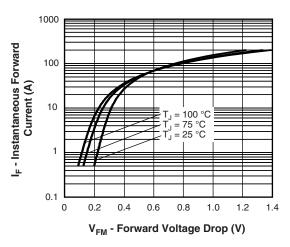


Fig. 1 - Maximum Forward Voltage Drop Characteristics

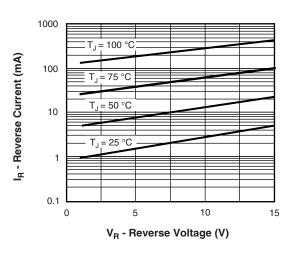


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

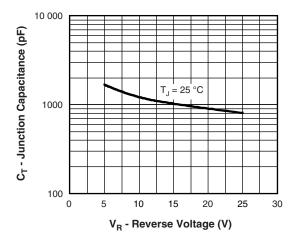


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

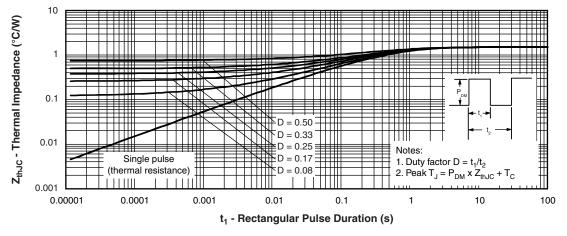


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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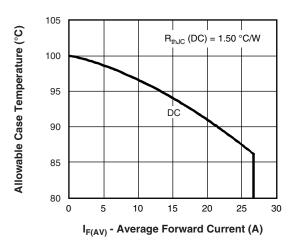


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

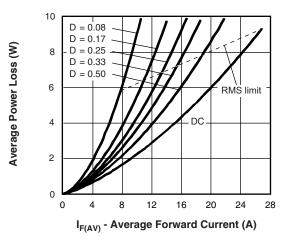


Fig. 6 - Forward Power Loss Characteristics

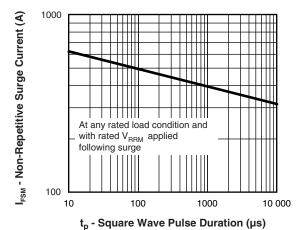


Fig. 7 - Maximum Non-Repetitive Surge Current

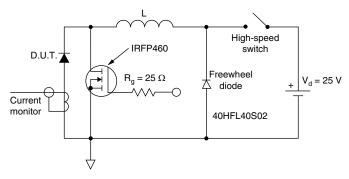


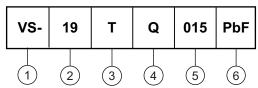
Fig. 8 - Unclamped Inductive Test Circuit

VS-19TQ015PbF, VS-19TQ015-N3

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ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

2 - Current rating (19 = 19 A)

Package:

T = TO-220

4 - Schottky "Q" series

5 - Voltage rating (015 = 15 V)

6 - Environmental digit

• PbF = Lead (Pb)-free and RoHS compliant

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-19TQ015PbF	50	1000	Antistatic plastic tube			
VS-19TQ015-N3	50	1000	Antistatic plastic tube			

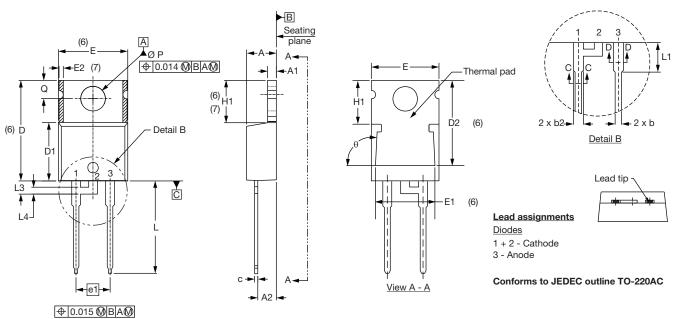
LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95221</u>				
Dort marking information	TO-220AC PbF	www.vishay.com/doc?95224		
Part marking information	TO-220AC -N3	www.vishay.com/doc?95068		



Vishay Semiconductors

TO-220AC

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	IETERS	INCHES		NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6
Е	10.11	10.51	0.398	0.414	3, 6

SYMBOL	MILLIM	IETERS	INCHES		NOTES
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
L3	1.78	2.13	0.070	0.084	
L4	0.76	1.27	0.030	0.050	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° t	o 93°	90° t	o 93°	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline



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